

RGWS00TS65

650V 50A Field Stop Trench IGBT

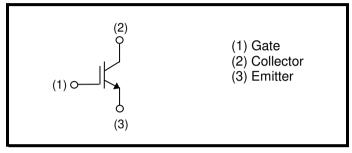
V_{CES}	650V
I _{C (100°C)}	50A
V _{CE(sat) (Typ.)}	1.6V
P_{D}	245W

Outline TO-247GE

Features

- 1) Low Collector Emitter Saturation Voltage
- 2) High Speed Switching
- 3) Low Switching Loss & Soft Switching
- 4) Pb free Lead Plating; RoHS Compliant

●Inner Circuit



Application

PFC

Solar converters

Mid to high switching frequency converters

Packaging Specifications

	 	
	Packaging	Tube
	Reel Size (mm)	-
Type	Tape Width (mm)	-
Type	Basic Ordering Unit (pcs)	600
	Packing Code	C13
	Marking	RGWS00TS65

● Absolute Maximum Ratings (at T_C = 25°C unless otherwise specified)

Parameter		Symbol	Value	Unit
Collector - Emitter Voltage		$V_{\sf CES}$	650	V
Gate - Emitter Voltage		V_{GES}	±30	V
Collector Current	T _C = 25°C	I _C	88	Α
	T _C = 100°C	I _C	54	Α
Pulsed Collector Current		I _{CP} *1	150	Α
Power Dissipation	T _C = 25°C	P_{D}	245	W
	T _C = 100°C	P_{D}	121	W
Operating Junction Temperature		T _j	-40 to +175	°C
Storage Temperature		T _{stg}	-55 to +175	°C

^{*1} Pulse width limited by T_{imax}.

●Thermal Resistance

Parameter	Symbol	Values			Unit
r arameter		Min.	Тур.	Max.	Offic
Thermal Resistance IGBT Junction - Case	$R_{\theta(j-c)}$	-	-	0.61	°C/W

●IGBT Electrical Characteristics (at T_j = 25°C unless otherwise specified)

Parameter	Symbol	Conditions		Unit		
raiaillelei	Symbol		Min.	Тур.	Max.	Offic
Collector - Emitter Breakdown Voltage	BV _{CES}	$I_{C} = 10 \mu A, V_{GE} = 0 V$	650	-	-	V
Collector Cut - off Current	I _{CES}	$V_{CE} = 650V, V_{GE} = 0V$	-	1	10	μΑ
Gate - Emitter Leakage Current	I _{GES}	$V_{GE} = \pm 30V$, $V_{CE} = 0V$	1	1	±200	nA
Gate - Emitter Threshold Voltage	$V_{GE(th)}$	$V_{CE} = 5V, I_{C} = 26.0 \text{mA}$	5.0	6.0	7.0	V
Collector - Emitter Saturation Voltage	V _{CE(sat)}	$I_{C} = 50A, V_{GE} = 15V,$ $T_{j} = 25^{\circ}C$ $T_{j} = 175^{\circ}C$	-	1.6 2.0	2.0	V

●IGBT Electrical Characteristics (at T_j = 25°C unless otherwise specified)

Dorometer	Symbol	Canditions	Values			Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Offic
Input Capacitance	C _{ies}	$V_{CE} = 30V$,	-	3320	-	
Output Capacitance	C _{oes}	$V_{GE} = 0V$,	-	83	-	рF
Reverse transfer Capacitance	C _{res}	f = 1MHz	-	60	-	
Total Gate Charge	Q_g	$V_{CE} = 400V$,	-	108	-	
Gate - Emitter Charge	Q_ge	$I_{\rm C} = 50A$,	-	22	-	nC
Gate - Collector Charge	Q_{gc}	V _{GE} = 15V	-	42	-	
Turn - on Delay Time	t _{d(on)}		-	46	-	
Rise Time	t _r	$I_C = 50A, V_{CC} = 400V,$ $V_{GF} = 15V, R_G = 10\Omega,$	_	20	-	ns
Turn - off Delay Time	t _{d(off)}	$T_i = 25^{\circ}C$	-	145	-	
Fall Time	t _f	Inductive Load	-	38	-	
Turn - on Switching Loss	E _{on}	*E _{on} include diode reverse recovery	-	0.98	-	I
Turn - off Switching Loss	E _{off}	,	-	0.91	-	mJ
Turn - on Delay Time	t _{d(on)}		-	43	-	
Rise Time	t _r	$I_C = 50A, V_{CC} = 400V,$ $V_{GF} = 15V, R_G = 10\Omega,$	-	24	-	no
Turn - off Delay Time	t _{d(off)}	$T_i = 175^{\circ}C$	-	165	-	ns
Fall Time	t _f	Inductive Load *E _{on} include diode reverse recovery	-	78	-	
Turn - on Switching Loss	E _{on}		-	1.02	-	m l
Turn - off Switching Loss	E _{off}		-	1.19	-	mJ
Reverse Bias Safe Operating Area	RBSOA	$I_C = 150A$, $V_{CC} = 520V$ $V_P = 650V$, $V_{GE} = 15V$ $R_G = 100\Omega$, $T_j = 175^{\circ}C$	FU	LL SQUA	.RE	-

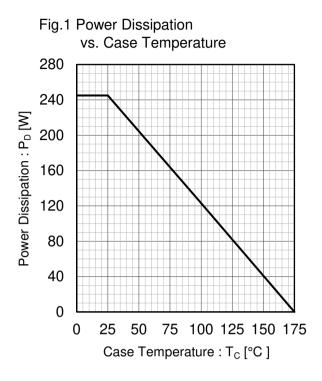


Fig.2 Collector Current vs. Case Temperature 100 80 Collector Current : Ic [A] 60 40 20 T_i ≤ 175°C _{GE} ≥ 15V 0 25 50 75 100 125 150 175 0 Case Temperature : T_C [°C]

Fig.3 Forward Bias Safe Operating Area

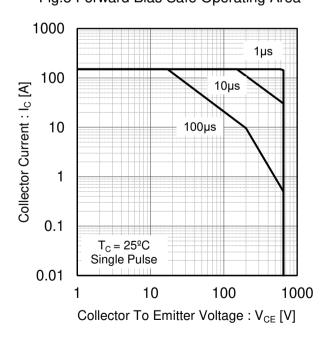


Fig.4 Reverse Bias Safe Operating Area

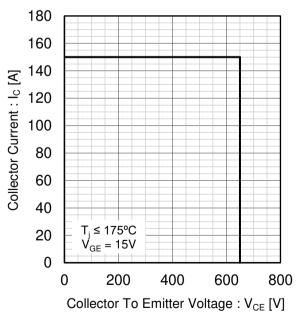


Fig.5 Typical Output Characteristics

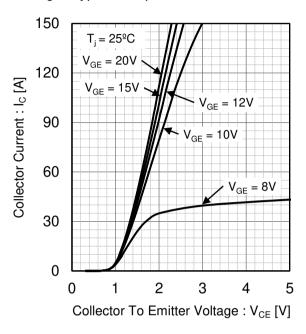


Fig.6 Typical Output Characteristics

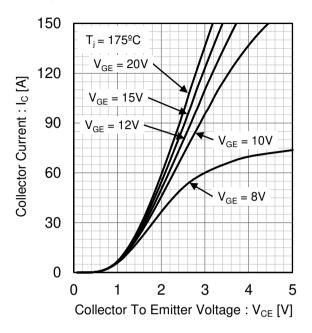


Fig.7 Typical Transfer Characteristics

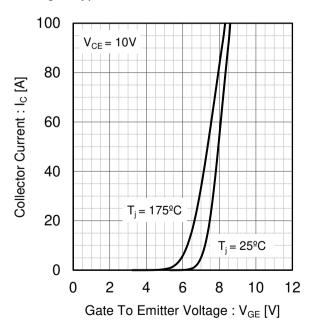
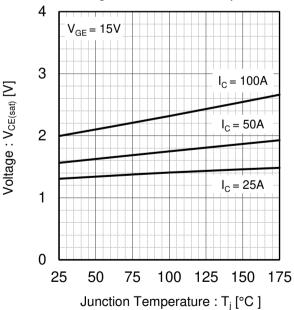


Fig.8 Typical Collector to Emitter Saturation Voltage vs. Junction Temperature



Collector To Emitter Saturation

Fig.9 Typical Collector to Emitter Saturation Voltage vs. Gate to Emitter Voltage

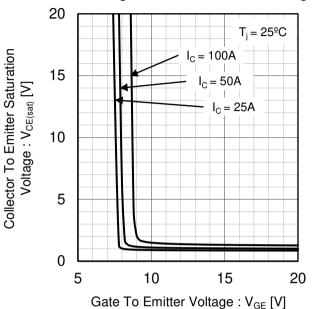


Fig.10 Typical Collector to Emitter Saturation Voltage vs. Gate to Emitter Voltage

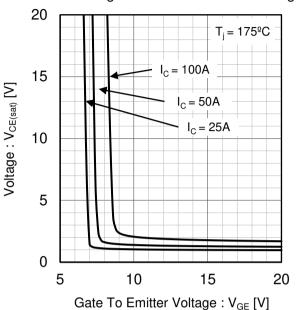


Fig.11 Typical Switching Time vs. Collector Current

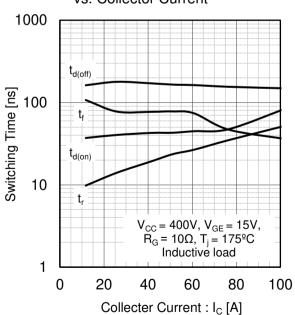
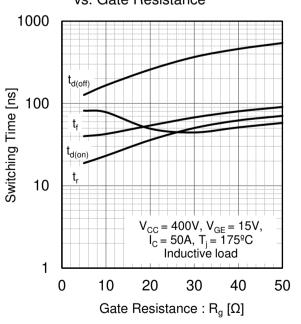


Fig.12 Typical Switching Time vs. Gate Resistance



Collector To Emitter Saturation

0

20

● Electrical Characteristic Curves

Fig.13 Typical Switching Energy Losses vs. Collector Current

10

| Fig. 13 Typical Switching Energy Losses vs. Collector Current

10

| Fig. 13 Typical Switching Energy Losses vs. Collector Current

| Voc. = 400V, Voc. = 15V, Rown of the state of the

40

60

Collecter Current : I_C [A]

80

100

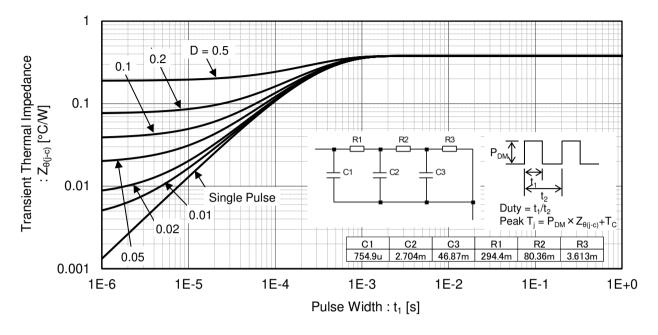
vs. Gate Resistance 10 E_{off} $V_{CC} = 400V, I_{C} = 50A, V_{GE} = 15V, T_{j} = 175^{\circ}C$ Inductive load 0.01 $0 \quad 10 \quad 20 \quad 30 \quad 40 \quad 50$ Gate Resistance : R_{G} [Ω]

Fig.14 Typocal Switching Energy Losses

Fig.15 Typical Capacitance vs. Collector to Emitter Voltage 10000 Cies 1000 Capacitance [pF] C_{oes} 100 C_{res} 10 f = 1MHz $V_{GE} = 0V$ $T_i = 25^{\circ}C$ 1 0.01 0.1 1 10 100 Collector To Emitter Voltage: V_{CE} [V]

Fig.16 Typical Gate Charge 15 Gate To Emitter Voltage: VGE [V] 10 5 $V_{CC} = 400V$ $I_C = 50A$ $T_i = 25^{\circ}C$ 0 0 20 40 60 80 100 120 Gate Charge : Qg [nC]

Fig.17 Typical IGBT Transient Thermal Impedance



Inductive Load Switching Circuit and Waveform

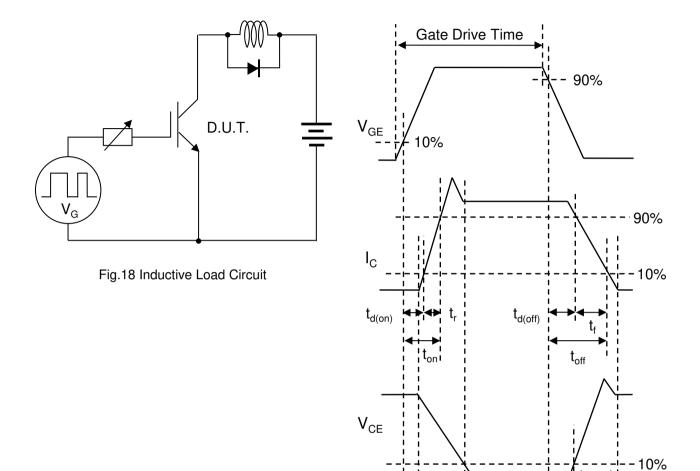


Fig.19 Inductive Load Waveform

Eon

 $V_{\text{CE}(\text{sat})}$

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